

TOSHIBA Transistor Silicon NPN Triple Diffused Type

2SC5549

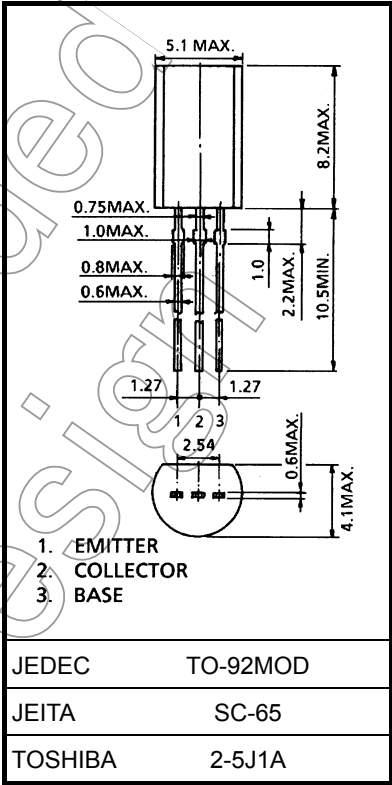
High-Speed Switching Application for Inverter Lighting System

Unit: mm

- Suitable for RCC circuits. (guaranteed small current  $h_{FE}$ )  
:  $h_{FE} = 13$  (min) ( $I_C = 1$  mA)
- High speed:  $t_r = 0.5$   $\mu$ s (max),  $t_f = 0.3$   $\mu$ s (max) ( $I_C = 0.24$  A)
- High breakdown voltage:  $V_{CEO} = 400$  V

Absolute Maximum Ratings ( $T_a = 25^{\circ}\text{C}$ )

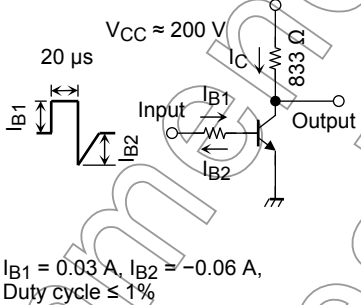
Characteristics		Symbol	Rating	Unit
Collector-base voltage		$V_{CBO}$	400	V
Collector-emitter voltage		$V_{CEO}$	400	V
Emitter-base voltage		$V_{EBO}$	7	V
Collector current	DC	$I_C$	1	A
	Pulse	$I_{CP}$	2	
Base current		$I_B$	0.5	A
Collector power dissipation		$P_C$	0.9	W
Junction temperature		$T_j$	150	$^{\circ}\text{C}$
Storage temperature range		$T_{stg}$	-55 to 150	$^{\circ}\text{C}$



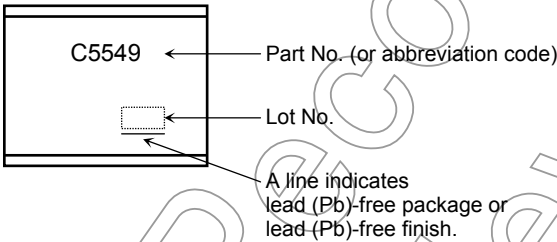
Weight: 0.36 g (typ.)

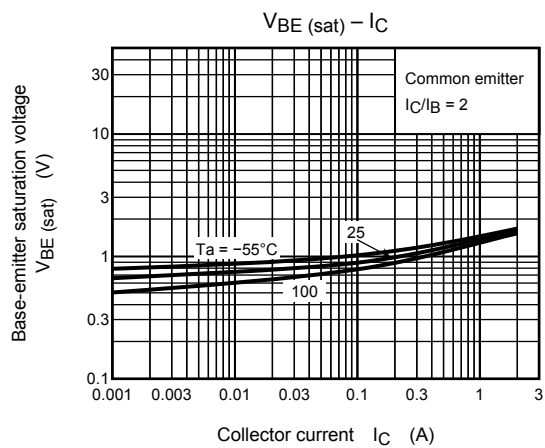
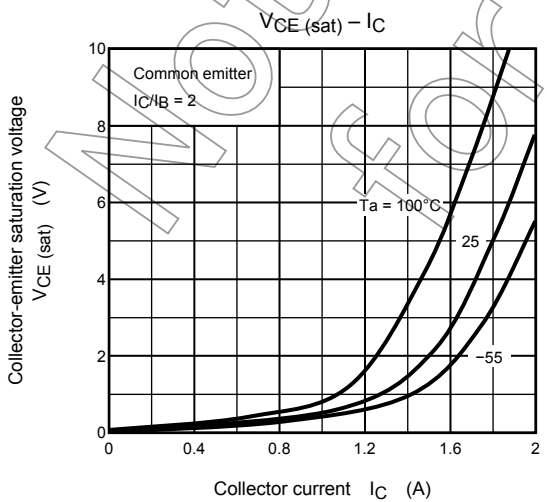
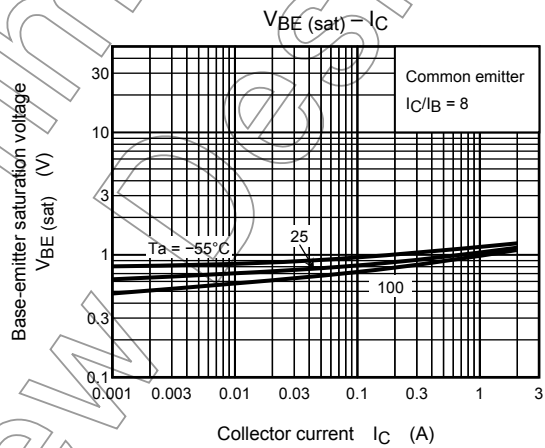
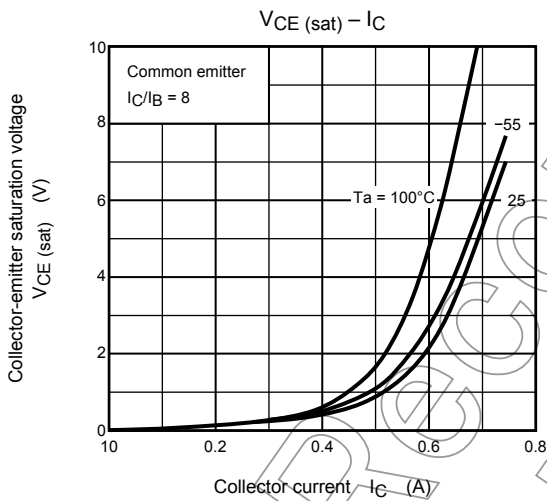
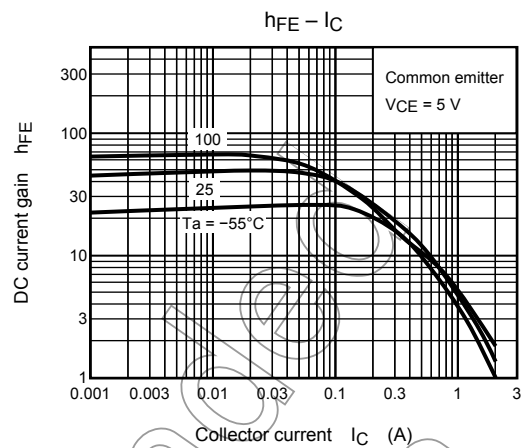
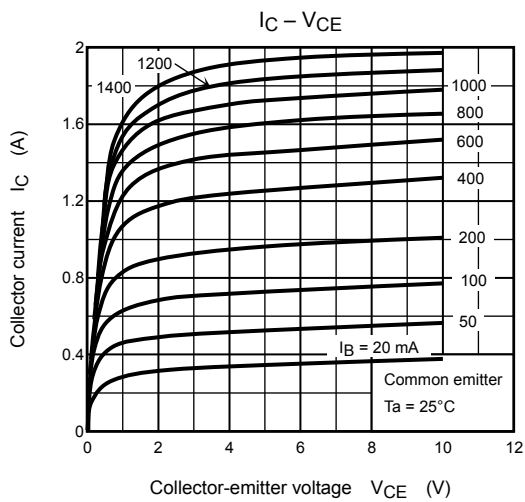
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

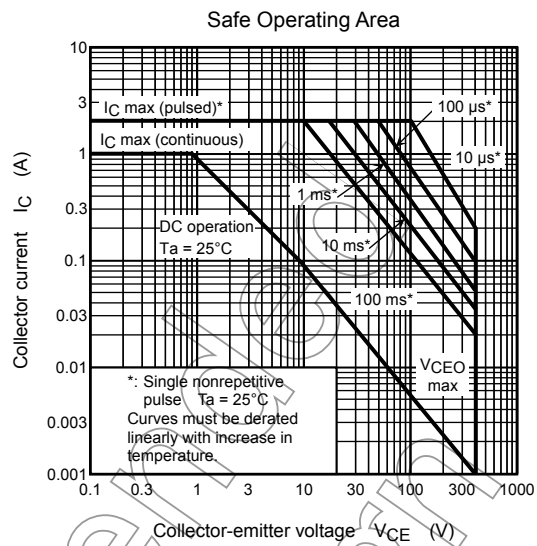
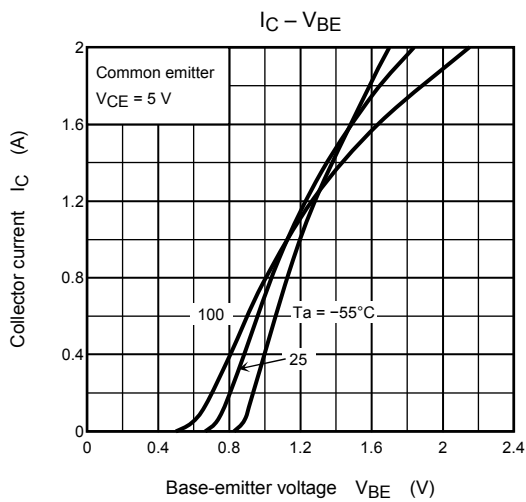
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		ICBO	V <sub>CB</sub> = 320 V, I <sub>E</sub> = 0	—	—	100	μA
Emitter cut-off current		IEBO	V <sub>EB</sub> = 7 V, I <sub>C</sub> = 0	—	—	100	μA
Collector-base breakdown voltage		V (BR) CBO	I <sub>C</sub> = 1 mA, I <sub>E</sub> = 0	400	—	—	V
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	400	—	—	V
DC current gain	h <sub>FE</sub> (1)		V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA	13	—	—	
	h <sub>FE</sub> (2)		V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.04 A	20	—	65	
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = 0.2 A, I <sub>B</sub> = 25 mA	—	—	1.0	V
Base-emitter saturation voltage		V <sub>BE</sub> (sat)	I <sub>C</sub> = 0.2 A, I <sub>B</sub> = 25 mA	—	—	1.3	V
Switching time	Rise time	t <sub>r</sub>	 V <sub>CC</sub> ≈ 200 V 20 μs I <sub>B1</sub> = 0.03 A, I <sub>B2</sub> = -0.06 A, Duty cycle ≤ 1%	—	—	0.5	μs
	Storage time	t <sub>stg</sub>		—	—	5.0	
	Fall time	t <sub>f</sub>		—	—	0.3	

Marking







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